PCN Num	iber:	2016	12070	104			PCN Date:	Dec. 09 2016	
Title:	Qualificat	ion of a	dditio	nal Assem	bly and Te	est sites for select	t Devices		
Customer PCN Mar			anager		Dept:	Quality Service	ic.		
Contact:	at	1 CIV MC	anușci	•	рерг.	Quality Service	: 5		
Proposed Date:	l 1 st Ship		Mar 0	9 2017	Estima	ited Sample Ava	ailability:	Provided upon Request	
Change T	уре:								
Asse	embly Site			Assembly				['] Materials	
Des			44		Specificat			Mechanical Specification	
	Site		14		Shipping/L			Test Process	
	er Bump Si				mp Materi			mp Process	
war	er Fab Site				b Materials		_ Wafer Fal	b Process	
					ber chang				
	6.01				PCN Det	alis			
Descripti	on of Chai	nge:							
	on differen	ces are				tional site. For th		Group #1, ─	
	Wha				UTAC		mkor	_	
Mount Comp									
					SID#PZ003		01375281		
Test cover	Mold Bond	Compo Wire/I	ound Diame	ster /	SID#CZ016 Au, 1.0 mi	SID#10	01376660 1.0 mils	verified with test	
MQ. Reason for	Mold Bond rage, insert	Compo Wire/[ions, co	ound Diame	ster /	SID#CZ016 Au, 1.0 mi	54 SID#1	01376660 1.0 mils	verified with test	
MQ. Reason for Continuity	Mold Bond rage, insert or Change of Supply	Compo I Wire/I ions, co	ound Diame ondition	eter /	ID#CZ010 Au, 1.0 mi main consi	stent with current	01376660 1.0 mils t testing and		
MQ. Reason for Continuity	Mold Bond rage, insert or Change of Supply	Compo I Wire/I ions, co	ound Diame ondition	eter /	ID#CZ010 Au, 1.0 mi main consi	SID#10	01376660 1.0 mils t testing and		
MQ. Reason for Continuity Anticipat None	Mold Bond rage, insert or Change of Supply ed impact	Compo	ound Diame ondition	ons will ren	nain consi	stent with current	01376660 1.0 mils t testing and		
MQ. Reason for Continuity Anticipat None	Mold Bond rage, insert or Change of Supply	Compo	ound Diame ondition	ons will ren	nain consi	stent with current	01376660 1.0 mils t testing and		
Reason for Continuity Anticipat None Anticipat I No I the	Mold Bond rage, insert or Change of Supply ed impact	Compo	pund Diame Dia Diame Diame Diame Diame Diame Diame Diame Diame Diame Diame Diame Dia Diame Dia Diame Dia Dia Dia Dia Dia Dia Dia Dia Dia Dia	m, Function I Declarate aterial Decoduction declarate in the second control of the seco	ion larations of ata and wition release	stent with current	1.0 mils t testing and v (positive / n at reports are llowing the pre-	driven from oduction release.	
Reason for Continuity Anticipat None Anticipat the Deci	mold Bond Bond rage, insert or Change of Supply ed impact ed impact impact to Material	Compositions, co	, Form	m, Function I Declarate aterial Declarate coduction do production do no production declarate coduction de	on, Qualitations of ata and wition releases	y or Reliability or Product Contential be available folse the revised reports.	1.0 mils t testing and v (positive / n at reports are llowing the pre-	driven from	
Reason for Continuity Anticipat None Anticipat the Deco Changes	Mold Bond Bond Page, insert or Change of Supply ed impact ed impact impact to Material laration	Compo	, Form	m, Function I Declarate aterial Declarate coduction do production do no production declarate coduction de	ion larations of ata and wittion releaseste. large from	y or Reliability or Product Contential be available folse the revised reports.	1.0 mils t testing and v (positive / n at reports are llowing the proorts can be o	driven from	
Reason for Continuity Anticipat None Anticipat I No I the Deci	Mold Bond Bond rage, insert or Change of Supply ed impact ed impact impact to Material laration	Compo	, Fori	m, Function I Declarate aterial Declarate oduction do production do production do production do production do production results.	ion larations of ata and wittion releaseste. large from	stent with current y or Reliability or Product Contential be available foliate the revised report.	1.0 mils t testing and very serious treports are ports can be on the property of the property	driven from oduction release btained from the	
Reason for Continuity Anticipat None Anticipat the Deci	Mold Bond Bond rage, insert or Change of Supply ed impact to Material laration to product to produc	Compo	, Fori	m, Function I Declarate aterial Decrease on production do production do production do production do production resulting e Origin (22)	ion larations of ata and wittion releaseste. large from	y or Reliability or Product Contential be available foliate the revised report this PCN:	(positive / note that reports are allowing the proports can be only as a second	driven from oduction release. btained from the sembly City angpakong	
MQ. Reason for Continuity Anticipat None Anticipat I have been been been been been been been be	Mold Bond Bond rage, insert or Change of Supply ed impact to Material laration to product to produc	Compo	, Fori	m, Function I Declarate aterial Decrease on production do production do production do production result de Origin (22) S2	ion larations of ata and wittion releaseste. large from	y or Reliability or Product Contential be available foliate the revised report this PCN: Dly Country Code (2) THA	1.0 mils t testing and very serious treports are ports can be on the property of the property	driven from oduction release. btained from the sembly City	

Sample product shipping label (not actual product label)





(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483\$I2 (P) (2P) REV: (V) 0033317 (20L) C\$0: SHE (21L) CCO: USA (22L) A\$0: MLA (23L) ACO: MYS

LBL: 5A (L)TO:1750

Topside Device marking (if included):

Assembly site code for NS2= B

Assembly site code for AKR = 4

Assembly site code for HNT = H

Product Affected

OPT: ITEM:

Group 1 Devices - Add Amkor Assembly/Test:

MAX222CDW	MAX222IDW	MAX222IDWRG4	ULN2803ADWG4
MAX222CDWG4	MAX222IDWG4	TRS222IDWR	ULN2803ADWR
MAX222CDWR	MAX222IDWR	ULN2803ADW	ULN2803ADWRG4
MAX222CDWRG4			

Group 2 Device - Add Hana Thailand Assembly/Test:

LM4040B20IDCKR



TI Information Selective Disclosure

Qualification Report

New Package: Amkor SOIC - 18DW Wide SOIC Offload (Cu Wire, NiPdAu finish)
Approve Date 03-Nov-2016

Product Attributes

Attributes	Qual Device: MAX222IDWR	Qual Device: ULN2803ADWR	
Assembly Site	AMKOR AP1	AMKOR AP1	
Package Family	SOIC	SOIC	
Wafer Fab Supplier	DFAB	SFAB	
Wafer Process	LBC3S	JI1	
Flammability Rating	UL 94 V-0	UL 94 V-0	

⁻ QBS: Qual by Similarity

⁻ Qual Devices qualified at LEVEL2-260C: MAX222IDWR, ULN2803ADWR

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: MAX222IDWR.	Qual Device: ULN2803ADWR.
AC	Autoclave 121C	96 Hours	3/231/0	3/231/0
AC	Autoclave 121C	144 Hours	3/231/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	1/30/0
FLAM	Flammability (IEC 695-2-2)		-	3/15/0
FLAM	Flammability (UL 94V-0)		-	3/15/0
FLAM	Flammability (UL-1694)		-	3/15/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0
HAST	Biased HAST, 130C/85%RH	192 Hours	-	3/231/0
HTOL	Life Test, 150C	300 Hours	-	1/76/0 (Note 1)
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0
LI	Lead Fatigue	Leads	-	3/66/0
LI	Lead Pull to Destruction	Leads	-	3/66/0
LFA	Lead Finish Adhesion	Leads	-	3/45/0
SD	Solderability	Pb	-	3/66/0
SD	Solderability	Pb Free	-	3/66/0
PD	Physical Dimensions	-	-	3/15/0
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0	3/231/0
TC	Temperature Cycle, -65/150C	750 Cycles	-	3/231/0
DS	Die Shear	Die	-	3/30/0
MQ	Manufacturability	(per mfg. Site specification)	-	Pass
WBP	Bond Pull	Wires	3/228/0	3/90/0
WBS	Ball Bond Shear	Wires	3/228/0	3/90/0
XR	X-ray	(top side only)	-	3/15/0
	-			_

Salt Atmosphere - Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Note (1): 1 unit lost during test, discounted.

⁻ The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours - The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

⁻ The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles



Qualification Report

Qualify HNT as an alternate site for LM4040B20IDCKR Approve Date 11-Nov-2016

Product Attributes

Attributes	Qual Device: LM4040B20IDCKR	QBS Product Reference: LM4040C201DBZR	QBS Process Reference: TL4242QKTTRQ1	QBS Package Reference: DG9411DCKR
Assembly Site	HNT	SHE	NFME	HNT
Package Family	SOT	SOT	TO-263	SOT
Wafer Fab Supplier	SFAB	SFAB	SFAB	FFAB
Wafer Process	JI2	JI2	JI2	ASL3C
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V 0

⁻ QBS: Qual By Similarity - Qual Device LM4040B20IDCKR is qualified at LEVEL1-260CG

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: LM4040B20IDCKR	QBS Product Reference: LM4040C201DBZR	QBS Process Reference: TL4242QKTTRQ1	QBS Package Reference: DG9411DCKR
AC	Autoclave 121C	96 Hours	-	-	3/231/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	-	3/90/0	3/90/0
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	3/2400/0	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	-
HBM	ESD - HBM	2500 V	-	1/3/0	-	-
HBM	ESD - HBM	1500 V	-	-	1/3/0	-
CDM	ESD - CDM	1500 V	1/3/0	-	-	-
CDM	ESD - CDM	1000 V	-	1/3/0	-	-
HTOL	Life Test, 125C	1000 Hours	-	-	3/231/0	-
HTSL	High Temp. Storage Bake, 175C	500 Hours	-	-	1/45/0	-
HTSL	High Temp. Storage Bake, 150C	1000 cycles	-	-	-	3/231/0
LU	Latch-up	(per JESD78)	-	1/6/0	1/6/0	-
PD	Physical Dimensions	-	-	-	3/30/0	-
SD	Surface Mount Solderability	Pb	-	-	1/15/0	-
SD	Surface Mount Solderability	Pb Free	-	-	1/15/0	-
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	3/231/0	-
WBS	Ball Bond Shear, Cpk>1.67	Wires	-	-	1/30/0	-

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

WIRS

WIRS

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Bissed HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47: 35C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.tl.com/